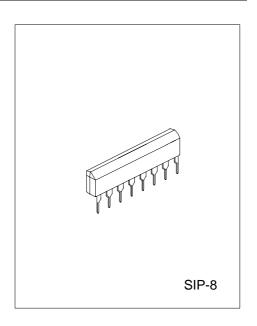
EARTH LEAKAGE CURRENT **DETECTOR**

DESCRIPTION

The UTC M54123L is a semiconductor integrated circuit with amplifier for a high-speed earth leakage circuit breaker.

FEATURES

- *Suitable for JIS C 8371
- *Good temperature characteristics of input sensitivity
- *High input sensitivity (V_T=6.1mV Typ.)
- *Low external component count
- *High noise and surge-proof
- *Low power dissipation (Pd=5mW Typ.) and may be used both as 100V and 200V.
- *Wide temperature range (Ta=-20~+80°C)



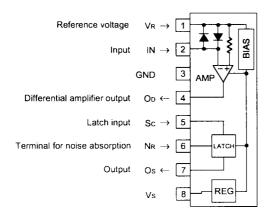
APPLICATION

*High speed earth leakage circuit breaker.

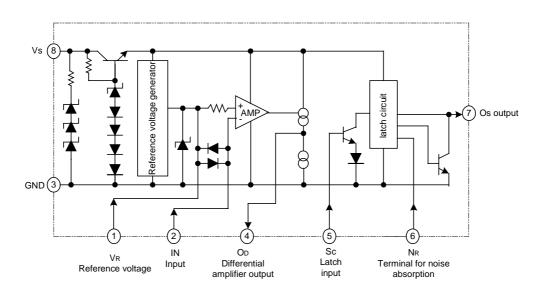
FUNCTION

The UTC M54123L circuit for the amplifying parts of earth leakage circuit breaker consists of differential amplifier, latch circuit and voltage regulator. It is connected to the secondary side of the zero current transformer (ZCT) which detects leakage current in the both input of the differential amplifier. Signals amplified by differential amplifier are integrated by an external capacitor, and connects to the input terminal of latch circuit with output suitable for the characteristics of high-speed earth leakage circuit breaker. Latch circuit keeps low in the output till the input voltage reaches the fixed level, and output becomes high when the leakage current more than fixed flows. It drives a thyristor connected to the output terminal of latch circuit.

PIN CONFIGURATIONS (TOP VIEW)



BLOCK DIAGRAM



ABSOLUTE MAXIMUM RATINGS (Ta=-20~80°C, unless otherwise noted)

PARAMETER	SYMBOL	CONDITIONS	RATINGS	UNIT	
Supply current	Is		8	mA	
VR pin current		Between VR-IN (Note 1)	250		
	Ivr	Between VR-GND	mA		
		Between IN-VR(Note 1)	-250		
IN terminal current		Between IN-V _R (Note 1) 250			
	lin	Between IN-GND	30	mA	
		Between VR-IN (Note 1)	-250		
Sc terminal current	Isc		5	mA	
Power dissipation	Pd		200	mV	
Operating temperature	Topr		-20 to +80	°C	
Storage temperature	Tstg		-55 to +125	°C	

Note 1: Current value between VR and IN, and between IN and VR is less than 1ms in the pulse width, and duty cycle is less than 12%, In applying AC current continuously, it is 100 mA in the off-state.

Remarks: GND terminal (pin 3 of the circuit is a basis of all the voltage except differential input clamp voltage of DC electrical characteristics, and direction of current is plus(no signal) in flowing into the circuit and is minus(-signal)in flowing out of it. Maximum value and minimum one are shown as absolute value. Please do not apply voltage whose standard is GND terminal in VR and IN pin.

RECOMMENDED OPERATING CONDITIONS (Ta=-20~+80°C, unless otherwise noted)

PARAMETER	SYMBOL	LIMITS			UNIT
		MIN	TYP	MAX	
Supply Voltage when latch circuit is off-state	Is	12			V
External capacitor between Vs and GND	Cvs	1			μF
External capacitor between Os and GND	Cos			1	μF

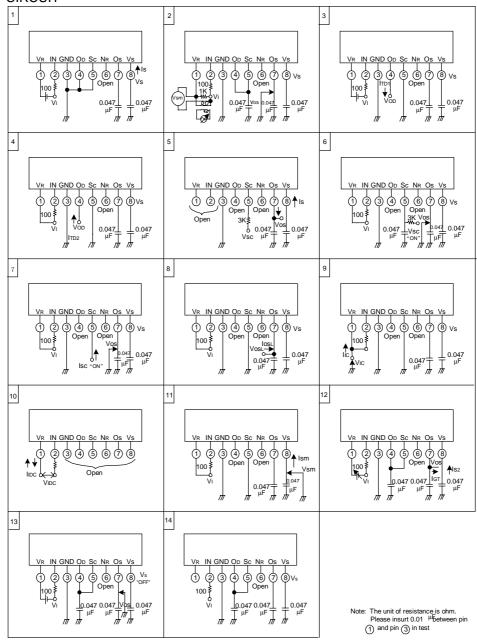
ELECTRICAL CHARACTERISTICS (Ta=-20~+80°C, unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS				LIMITS			UNIT
				TEMPERA	TEST	MIN	TYP*	MAX	
				-TURE	CIRCUIT				
				(°C)					
Supply current	ls1	Vs=12V,VR-V1=30mV		-20	1			580	μΑ
				25	1		400	530	
				80	1			480	
Trip voltage	VT	Vs=16V, Vi	R-V1(Note2)	-20~+80	2	4	6.1	9	mV
Timed current1	ITD1	Vs=16V, VR-V1=30mV VoD=1.2V		25	3	-12		-30	μΑ
Timed current2	ITD2	Vs=16V, short circuit between VR and V1, VoD=0.8V		25	4	17		37	μΑ
Output current	lo	Vsc=1.4V, Vos=0.8V,	Is1=580μA	-20	5	-200			
			Is1=530μA	25	5	-100			μΑ
			Is1=480μA	80	5	-75			
Sc "ON" voltage (Note3)	Vsc"on"	Vs=16V		25	6	0.7		1.4	V
Sc input current	Isc"on"	Vs=12V		25	7			5	μΑ

PARAMETER	SYMBOL	TEST CONDITIONS			LIMITS			UNIT
			TEMPERA	TEST	MIN	TYP*	MAX	
			-TURE	CIRCUIT				
			(°C)					
Output low-level current	losl	Vs=12V,Vosl=0.2V	-20~+80	8	200			μΑ
Input clamp voltage	Vic	Vs=12V, IIC=20mA	-20~+80	9	4.3		6.7	V
Differential input clamp	VIDC	IIDC=100mA	-20~+80	10	0.4		2	V
voltage								
Maximum current voltage	Vsм	Ism=7mA	25	11	20		28	V
Supply current 2(Note 4)	ls2	VR-V1, Vos=0.6V	-20~+80	12			900	μΑ
		(Note 5)						
Latch circuit is off-state	\/a ====		25	13	0.5			V
supply voltage (Note6)	Vs "OFF"							
Operating time (Note 7)	Ton	Vs=16V,VR-V1=0.3V	25	14	2		4	ms

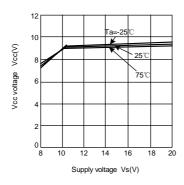
- Note 2: When standard value of voltage (60Hz) between VR and VI is minimum, and output Os is low-level, or when standrd value of voltage(60Hz)between VR and VI is maximum, and output Os is high-level, it is considered
- Note 3: When standard value of voltage Vsc"on" is minimum, and output Os is low-level, or when standard value of voltage Vsc"on" is maximum, and output Os is high-level, it is considered as a good one.
- Note 4: Supply current 2 is necessary to keep high in output Os.
- Note 5: After applying 30mV between VR and VI and shorting between them,it is considered as a good one if standard value of Igt flows out of output Os
- Note 6: After supply voltage applies 12V and output Os is high-level, it is considered as a good one in the standard value of supply voltage and in the low-level of output Os.
- Note 7: Operating time is a time from applying fixed input till operating latch circuit in 0.047μF between O_D and

TEST CIRCUIT



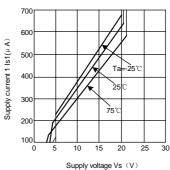
TYPICAL CHARACTERISTICS

Vcc voltage vs.supply voltage

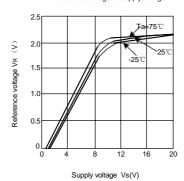


Vcc voltage generates by the constant voltage circuit in IC. This is measured not by M54123L but by a special element.

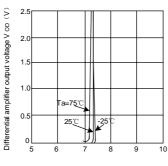
Supply current 1 vs.supply voltage



Reference voltage vs.supply voltage

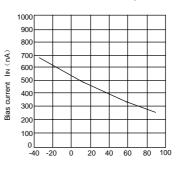


Differential amplifier output voltage vs. differential input voltage



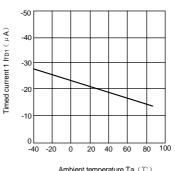
 $\mbox{Differential input voltage} \ \triangle \mbox{Vi=VR-Vin} \ \ (\mbox{mV})$

Bias current vs. ambient temperature



Ambient temperature Ta (°C)

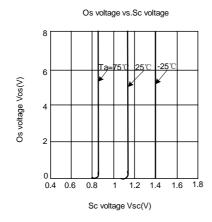
Timing current vs. ambient temperature

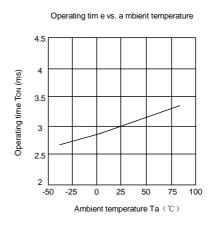


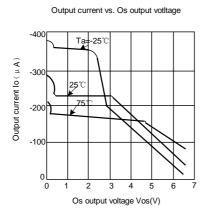
UNISONIC TECHNOLOGIES CO., LTD.

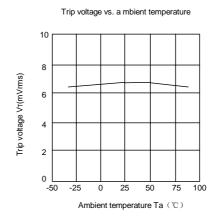
QW-R122-001,A

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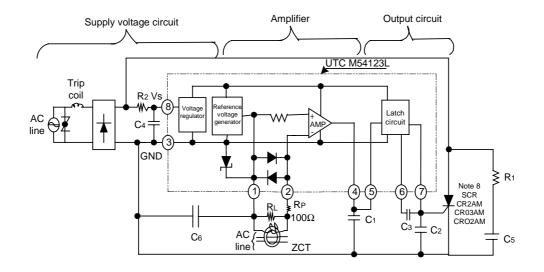




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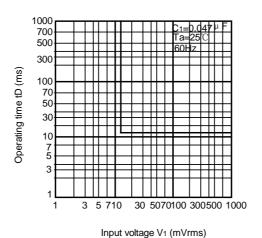
APPLICATION CIRCUIT

HIGH-SPEED LEAKAGE CIRCUIT BREAKER WITH UTC M54123L



Note 8:Gate current must be selected.
Please select voltage resistance by AC supply voltage

Operating time vs.input voltage



Supply voltage circuit is connected as a previous diagram. Please decide constants R1, R2, C4, and C5 of a filter in order to keep at least 12V in Vs, when normal, supply current flows.

In this case, please connect C4 (more than 1 µ F) and C2(less than 1 µ F). ZCT and load resistance R_L of ZCT are connected between input pin 1 and 2. In this case protective resistance $(Rp=100\,\Omega)$ must be insurted. Sensitivity current is regulated by R_L, and output of amplifier shows in pin 4. External capacitor C1 between pin 4 and GND is used for noise removal.

When large current is grounded in the primary side (AC line) of ZCT, the wave form in the secondary side of ZCT is distorted and some signals does not appear in the output of amplifier. So please connect a varistor or a diode (2

Latch circuit is used to inspect the output level of amplifier and to supply gate current on the external SCR. When input pin becomes more than 1.1V (Typ.), latch circuit operate and supply gate current in the gate of SCR connected to the output pin 7. Pin 6 can be used in the open state, but please connect capacitor (about 0.047 μ F) between pin 6 and pin 7.

Capacitor C6 between pin 1 and GND is used to remove noise and is about $0.047\,\mu$ F.